NSN 5962-01-395-2865

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+155.0 degrees celsius
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
50.00 milliamperes forward current, peak total value not applicable
Terminal Surface Treatment:
Solder
Product Name:
Memory, digital, cmos, 4k x 9 fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds access
Memory Device Type:
First-in first-out
Test Data Document:
96096-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A458a0